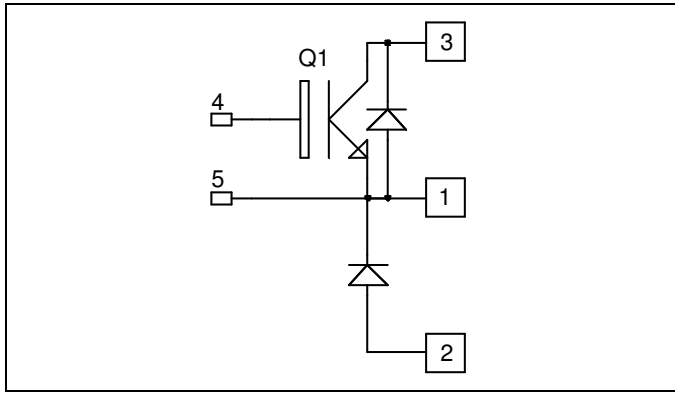


***Buck chopper  
Trench IGBT® Power Module***

**$V_{CES} = 1700V$   
 $I_C = 300A @ T_c = 80^\circ C$**



**Application**

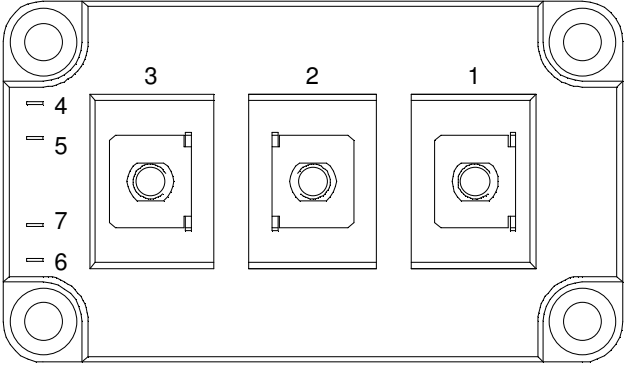
- AC and DC motor control
- Switched Mode Power Supplies

**Features**

- Trench + Field Stop IGBT® Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - Avalanche energy rated
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Low stray inductance
- High level of integration
- Kelvin emitter for easy drive
- Low stray inductance
  - M6 power connectors

**Benefits**

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat



**Absolute maximum ratings**

| <i>Symbol</i> | <i>Parameter</i>                      |                     | <i>Max ratings</i> | <i>Unit</i> |
|---------------|---------------------------------------|---------------------|--------------------|-------------|
| $V_{CES}$     | Collector - Emitter Breakdown Voltage |                     | 1700               | V           |
| $I_C$         | Continuous Collector Current          | $T_C = 25^\circ C$  | 530                | A           |
|               |                                       | $T_C = 80^\circ C$  | 300                |             |
| $I_{CM}$      | Pulsed Collector Current              | $T_C = 25^\circ C$  | 600                |             |
| $V_{GE}$      | Gate - Emitter Voltage                |                     | $\pm 20$           | V           |
| $P_D$         | Maximum Power Dissipation             | $T_C = 25^\circ C$  | 1470               | W           |
| RBSOA         | Reverse Bias Safe Operation Area      | $T_j = 125^\circ C$ | 600A@1600V         |             |

**CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

All ratings @  $T_j = 25^\circ\text{C}$  unless otherwise specified

## Electrical Characteristics

| Symbol       | Characteristic                        | Test Conditions                | Min  | Typ   | Max        | Unit |
|--------------|---------------------------------------|--------------------------------|------|---|------------|------|
| $BV_{CES}$   | Collector - Emitter Breakdown Voltage | $V_{GE} = 0V, I_C = 8mA$       | 1700 |   |            | V    |
| $I_{CES}$    | Zero Gate Voltage Collector Current   | $V_{GE} = 0V, V_{CE} = 1700V$  |      |   | 8          | mA   |
| $V_{CE(on)}$ | Collector Emitter on Voltage          | $V_{GE} = 15V$<br>$I_C = 300A$ |      | $T_j = 25^\circ\text{C}$<br>$T_j = 125^\circ\text{C}$ | 2.0<br>2.4 | V    |
| $V_{GE(th)}$ | Gate Threshold Voltage                | $V_{GE} = V_{CE}, I_C = 12 mA$ | 5.2  | 5.8   | 6.4        | V    |
| $I_{GES}$    | Gate - Emitter Leakage Current        | $V_{GE} = 20V, V_{CE} = 0V$    |      |   | 400        | nA   |

## Dynamic Characteristics

| Symbol       | Characteristic               | Test Conditions  | Min | Typ  | Max | Unit |
|--------------|------------------------------|--|-----|------|-----|------|
| $C_{ies}$    | Input Capacitance            | $V_{GE} = 0V, V_{CE} = 25V$  |     | 26   |     | nF   |
| $C_{res}$    | Reverse Transfer Capacitance | $f = 1MHz$   |     | 0.9  |     |      |
| $T_{d(on)}$  | Turn-on Delay Time           | Inductive Switching ( $25^\circ\text{C}$ )<br>$V_{GE} = \pm 15V$<br>$V_{Bus} = 900V$<br>$I_C = 300A$<br>$R_G = 4.7\Omega$  |     | 280  |     | ns   |
| $T_r$        | Rise Time                    |  |     | 100  |     |      |
| $T_{d(off)}$ | Turn-off Delay Time          |  |     | 850  |     |      |
| $T_f$        | Fall Time                    |  |     | 120  |     |      |
| $T_{d(on)}$  | Turn-on Delay Time           | Inductive Switching ( $125^\circ\text{C}$ )<br>$V_{GE} = \pm 15V$<br>$V_{Bus} = 900V$<br>$I_C = 300A$<br>$R_G = 4.7\Omega$ |     | 330  |     | ns   |
| $T_r$        | Rise Time                    |  |     | 100  |     |      |
| $T_{d(off)}$ | Turn-off Delay Time          |  |     | 1000 |     |      |
| $T_f$        | Fall Time                    |  |     | 200  |     |      |
| $E_{off}$    | Turn Off Energy              |  |     | 95   |     | mJ   |

## Reverse diode ratings and characteristics

| Symbol   | Characteristic          | Test Conditions                                      | Min | Typ   | Max        | Unit     |
|----------|-------------------------|--|-----|---|------------|----------|
| $V_F$    | Diode Forward Voltage   | $I_F = 300A$<br>$V_{GE} = 0V$                        |     | $T_j = 25^\circ\text{C}$<br>$T_j = 125^\circ\text{C}$ | 1.8<br>1.9 | 2.2<br>V |
| $E_r$    | Reverse Recovery Energy | $I_F = 300A$<br>$V_R = 900V$<br>$di/dt = 900A/\mu s$ |     | $T_j = 25^\circ\text{C}$<br>$T_j = 125^\circ\text{C}$ | 35<br>70   | mJ       |
| $Q_{rr}$ | Reverse Recovery Charge | $I_F = 300A$<br>$V_R = 900V$<br>$di/dt = 900A/\mu s$ |     | $T_j = 25^\circ\text{C}$<br>$T_j = 125^\circ\text{C}$ | 75<br>125  | $\mu C$  |

## Thermal and package characteristics

| Symbol     | Characteristic  | Min           | Typ | Max | Unit             |                    |
|------------|---|---------------|-----|-----|------------------|--------------------|
| $R_{thJC}$ | Junction to Case  | IGBT          |     |     | 0.085            | $^\circ\text{C/W}$ |
|            |   | Diode         |     |     | 0.13             |                    |
| $V_{ISOL}$ | RMS Isolation Voltage, any terminal to case $t = 1$ min,<br>$I_{isol} < 1mA, 50/60Hz$ | 3500          |     |     | V                |                    |
| $T_J$      | Operating junction temperature range  | -40           |     | 150 | $^\circ\text{C}$ |                    |
| $T_{STG}$  | Storage Temperature Range   | -40           |     | 125 |                  |                    |
| $T_C$      | Operating Case Temperature  | -40           |     | 125 |                  |                    |
| Torque     | Mounting torque   | For terminals | M6  | 3   | 5                | N.m                |
|            |   | To Heatsink   | M6  | 3   | 5                |                    |
| Wt         | Package Weight  |               |     | 380 | g                |                    |

